N-Channel 80-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

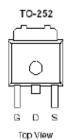
Typical Applications:

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I _D (A)	
80	82 @ V _{GS} = 10V	21	
80	110 @ V _{GS} = 4.5V	18	







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter			Symbol	Limit	Units	
Drain-Source Voltage				80	V	
Gate-Source Voltage				±20	V	
Continuous Drain Current		T _C =25°C	I_D	21	۸	
Pulsed Drain Current ^b			I _{DM}	80	Α	
Continuous Source Current (Diode Conduction)				35	Α	
Power Dissipation		T _C =25°C	P_{D}	50	W	
Operating Junction and Storage Temperature Range			T_J, T_{stq}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	40	°C/W			
Maximum Junction-to-Case	$R_{\theta JC}$	3	C/VV			

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Typical Electrical Characteristics

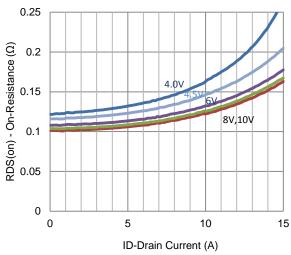
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zoro Gato Voltago Brain Garrent	.033	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10		
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$			82	mΩ	
Dialii-Source On-Nesistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 9.9 \text{ A}$			110	11152	
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A}$		8		S	
Diode Forward Voltage	V_{SD}	$I_S = 17.5 \text{ A}, V_{GS} = 0 \text{ V}$		1		V	
		Dynamic					
Total Gate Charge	Q_g			7		nC	
Gate-Source Charge	Q_gs	$V_{DS} = 40 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 10 \text{ A}$		2.9			
Gate-Drain Charge	Q_gd			3]	
Turn-On Delay Time	$t_{d(on)}$			3			
Rise Time	t _r	$V_{DS} = 40 \text{ V}, R_L = 4 \Omega, I_D = 10 \text{ A},$		4		nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		16		110	
Fall Time	t _f	<u> </u>		5			
Input Capacitance	C _{iss}			380			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		46		рF	
Reverse Transfer Capacitance	C_{rss}			29			

Notes

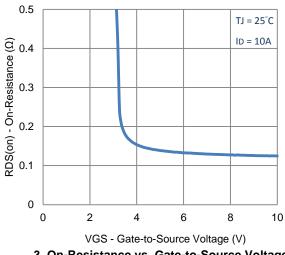
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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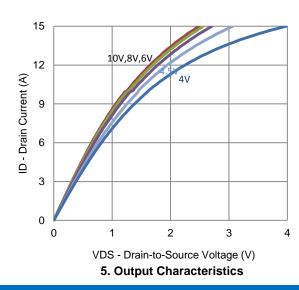
Typical Electrical Characteristics

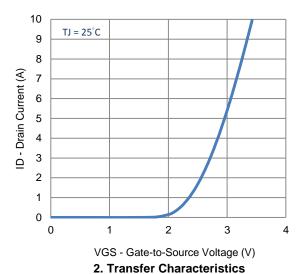


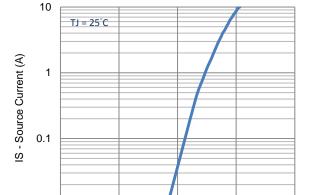
1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage





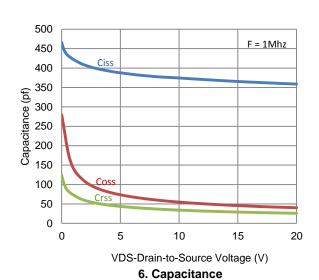


VSD - Source-to-Drain Voltage (V) 4. Drain-to-Source Forward Voltage

0.6

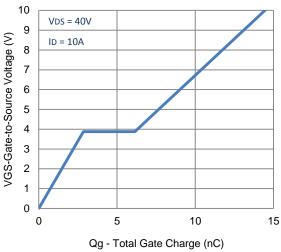
1.2

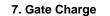
0.3

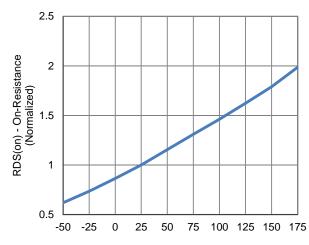


0.01

Typical Electrical Characteristics

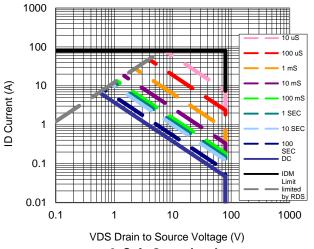




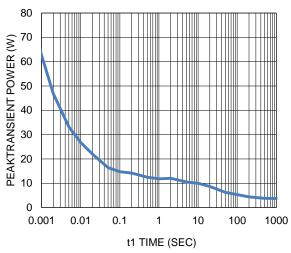


TJ - Junction Temperature (°C)

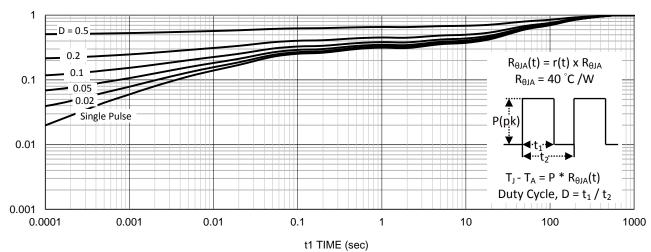
8. Normalized On-Resistance Vs **Junction Temperature**



9. Safe Operating Area

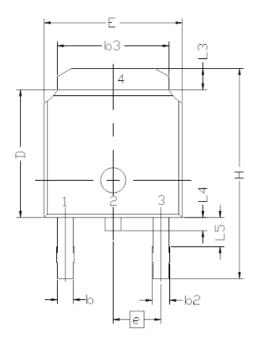


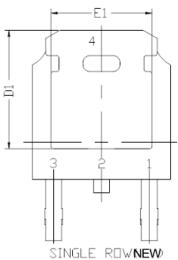
10. Single Pulse Maximum Power Dissipation

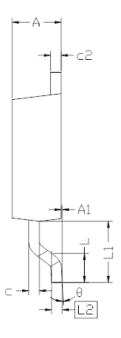


11. Normalized Thermal Transient Junction to Ambient

Package Information







CVADD	DIMENS:	IONAL F	REQMTS			
SYMBOL	MIN	NDM	MAX			
E	6.40	6.60	6.731			
L	1.40	1.52	1.77			
L1	2.743 REF					
L2	0.	.508 BS	_			
L3	0.89		1.27			
L4	0.64		1.01			
L5						
D	6.00	6.10	6,223			
Н	9.40	10.00	10.40			
b	0.64	0.76	0,88			
b2	0.77	0.84	1.14			
b3	5,21	5.34	5.46			
е	2.	286 BS	C			
Α	2,20	2.30	2.38			
A1	0		0.127			
	0.45	0.50	0,60			
c2	0.45	0.50	0.58			
D1	5,30					
E1	4.40					
θ	0°		10°			

Note:

- 1. All Dimension Are In mm.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.

Ordering Information

AM30N08-80D-T1-XX

A: Analog Power

- M: MOSFET

- 30N08-80D: Part number

– N: N-Channel

– T1: Tape & reel

– XX: Blank: Standard

PF: Leadfree